

SURFACE TREATMENTS FOR ALIGNMENT OF BLOCK COPOLYMERS

FIELD OF THE INVENTION

5 The present invention relates to a method for the synthesis and utilization of cross-linked substituted polystyrene copolymers as surface treatments (PXSTs) for control of the orientation of the physical features of a block copolymer deposited over the first copolymer. Such methods have many uses including multiple applications in the semiconductor industry including production of templates for nanoimprint lithography.

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BACKGROUND OF THE INVENTION

Appropriately structured block copolymers (BCs) self-assemble into regular patterns with features that are less than 100 nm [1] and can be exploited in nanomanufacturing applications such as microelectronics, solar cells, and membranes.

15 Hexagonally packed cylinders aligned perpendicular to the substrate surface are one of the more useful nanostructures for these applications. Multiple surface treatment techniques have been reported that enable this orientation including surface treatment with alkyl chlorosilanes [2, 3], chemical patterning [4-6], and polymer “brushes” [7-10]. However, control over feature size and orientation is still lacking. What is needed is a

20 method which provides a large process latitude in the necessary control over feature orientation.

SUMMARY OF THE INVENTION

The present invention relates to a method for the synthesis and utilization of random cross-linked substituted polystyrene copolymers as surface treatments (PXSTs)

for control of the orientation of the physical features of a block copolymer deposited over the first copolymer. Such methods have many uses including multiple applications in the semiconductor industry including production of templates for nanoimprint lithography. A wide range of surface energies can be obtained from these materials, and the results show the PXSTs need not be constituted from the identical two monomers in the block copolymer (BC) to obtain a wide process latitude for perpendicular orientation.

In one embodiment, the invention relates to a method, comprising: a) providing: i) a crosslinkable polymer comprising first and second monomers, ii) a block copolymer comprising third and fourth monomers, wherein said third and fourth monomers are chemically different from said first and second monomers; b) coating a surface with said crosslinkable polymer to create a first film; c) treating said first film under conditions such that crosslinkable polymer is crosslinked; d) coating said first film with said block copolymer to create a second film, and e) treating said second film under conditions such that nanostructures form, wherein the shape (and/or orientation) of the nanostructures is controlled (at least in part) by the chemical nature of said first film (and in some embodiments, it is also controlled in part by film thickness). In one embodiment, the block copolymer forms cylindrical nanostructures, said cylindrical nanostructures being substantially vertically aligned with respect to the plane of the first film. In one embodiment, said coating of step b) comprises spin coating. In one embodiment, the thickness of said first film is greater than 5.5 nm and less than 30 nm. In one embodiment, the thickness of said first film is between 10 and 30 nm. In one embodiment, said thickness of said first film is between 15 and 20 nm. In one embodiment, said crosslinkable polymer comprises an azido group on said first or

second monomer (although other crosslinkable groups are used in other embodiments).

In one embodiment, the PXST can contain one or several comonomers, the comonomers need not be those that are used to produce the block copolymer. In one embodiment,

said treating of said first film in step c) comprises heating. Alternatively said treating

5 comprises treating with light. Furthermore, in one embodiment said treating comprises

light and heat. In one embodiment, said third monomer is styrene and said block

copolymer comprises polystyrene. In one embodiment, said block copolymer is a

polystyrene-block-poly(methyl methacrylate) copolymer. In one embodiment, said

coating of said first film in step d) comprises spin coating. In one embodiment, wherein

10 the thickness of said second film is between 10 and 100 nm. In one embodiment, said

thickness of said second film is between 20 and 70 nm. In one embodiment, the treating

of step e) comprises heating (e.g. under vacuum) so that the film is annealed. In one

embodiment, the nanostructures are less than 100 nm in height.

In further embodiments, the invention relates to a composition, comprising a

15 second polymer film coated on a first polymer film, said first polymer film comprising

first and second monomers, said second polymer film comprising third and fourth

monomers, wherein said third and fourth monomers are chemically different from said

first and second monomers. In one embodiment, said second film comprises physical

structures on a nanometer scale or "nanostructures", said physical structures controlled

20 by the chemical nature of said first film. In one embodiment, said second film comprises

cylindrical nanostructures, said cylindrical nanostructures being substantially vertically

aligned with respect to the plane of the first film. In one embodiment, the nanostructures

are less than 100 nm in height (and more typically between 20 nm and 70 nm in height).

In one embodiment, said second film comprises a polystyrene-block-poly(methyl methacrylate) copolymer. In one embodiment, said first polymer film is coated on a surface. In one embodiment, said first polymer film is crosslinked. In one embodiment of the composition, the thickness of said first film is
5 between 10 and 30 nm. In other embodiments, said thickness of said first film is between 15 and 20 nm. In one embodiment, the thickness of said second film is between 10 and 100 nm. In other embodiments, said thickness of said second film is between 20 and 70 nm.

10 BRIEF DESCRIPTION OF THE DRAWINGS

For a more complete understanding of the features and advantages of the present invention, reference is now made to the detailed description of the invention along with the accompanying figures.

Figure 1 shows the synthesis of poly(styrene-b-methyl methacrylate)
15 (PS-b-PMMA). PS-b-PMMA was anionically synthesized via standard Schlenk line techniques [11, 12].

Figure 2 shows the Refractive Index detector response from a Gel Permeation Chromatography (RI GPC) of PS-b-PMMA.

Figure 3 shows the of a family of polymers with different surface energies made
20 by polymerization of monomers having a variety of different substituents. The characterization of P(SR)-r-P(SBnAz) and the impact of the various substituents are shown in Table 1.

Figure 4 shows the surface energies of PXSTs where R = tBu, Cl, Me, H, and Br (blue), homopolymers (red), and wafer (grey).

Figure 5 shows an atomic force microscopy (AMF) phase image of PS-b-PMMA on PXST where (R = Br).

5 Table 1 shows the characterization of P(SR)-r-P(SBnAz) (shown in Figure 3) with different substituents at the R position.

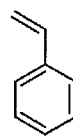
Figure 6 is a schematic which shows the difference between homopolymers, random polymers and block polymers.

10 **DEFINITIONS**

To facilitate the understanding of this invention, a number of terms are defined below. Terms defined herein have meanings as commonly understood by a person of ordinary skill in the areas relevant to the present invention. Terms such as “a”, “an” and “the” are not intended to refer to only a singular entity, but include the general class of
15 which a specific example may be used for illustration. The terminology herein is used to describe specific embodiments of the invention, but their usage does not delimit the invention, except as outlined in the claims.

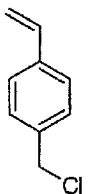
The present invention also contemplates styrene “derivatives” where the basic styrene structure is modified, e.g. by adding substituents to the ring (but preferably
20 maintaining the vinyl group for polymerization). Derivatives can be, for example, hydroxy-derivatives, oxo-derivatives or halo-derivatives. As used herein, “hydrogen” means -H; “hydroxy” means -OH; “oxo” means =O; “halo” means independently -F, -Cl, -Br or -I.

In addition, atoms making up the compounds of the present invention are intended to include all isotopic forms of such atoms. Isotopes, as used herein, include those atoms having the same atomic number but different mass numbers. By way of general example and without limitation, isotopes of hydrogen include tritium and deuterium, and isotopes of carbon include ^{13}C and ^{14}C . Similarly, it is contemplated that one or more carbon atom(s) of a compound of the present invention may be replaced by a silicon atom(s). Furthermore, it is contemplated that one or more oxygen atom(s) of a compound of the present invention may be replaced by a sulfur or selenium atom(s).

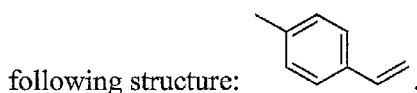


Styrene is represented by the following structure:

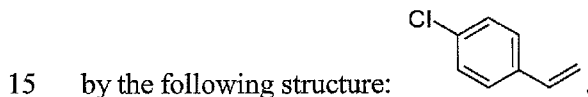
10 1-(chloromethyl)-4-vinylbenzene is represented by the following structure:



P-methylstyrene is an example of a styrene derivative and is represented by the



P-chlorostyrene is another example of a styrene haloderivative and is represented



It is desired that the second film deposited over the first film develop “physical features on a nanometer scale,” “nanofeatures” or “nanostructures” with controlled orientation. These physical features have shapes and thicknesses. For example,

various structures can be formed by components of a block copolymer, such as vertical lamellae, in-plane cylinders, and vertical cylinders, and may depend on surface energies and film thickness. In a preferred embodiment, the second film develops cylindrical nanostructures, said cylindrical structures being substantially vertically aligned with
5 respect to the plane of the first film. Orientation of structures in regions or domains at the nanometer level (i.e. “microdomains” or “nanodomains”) may be controlled to be approximately uniform. The methods described herein can generate structures with the desired size, shape, orientation, and periodicity. Thereafter, in one embodiment, these nanostructures may be etched or otherwise further treated.

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DETAILED DESCRIPTION OF THE INVENTION

Surface Energies of PXSTs. In the course of our efforts to employ non-traditional monomers for BCs, we became interested in the effect of surface energy on BC orientation. Films thicker than 15 nm of polymer 3 (Figure 3) were spin-coated,
15 heated to cross-link through the azide functionality, and thoroughly rinsed to remove any non-cross-linked materials. Surface energies of these films were obtained by goniometry with water, glycerol, and diiodomethane contact angles. Several measurements were made over the entire wafer, and the error was consistently +/- 2 dyne/cm. Figure 4 displays these data and shows that the substituents affect the surface
20 energy of the film. Additionally, the surface energies of non-cross-linked homopolymer films of PS and PMMA and a wafer cleaned with piranha were measured, and these values are consistent with the literature [2, 13].

In one embodiments, the invention relates to the PS-b-PMMA films of various thicknesses were coated on the PXSTs. These were annealed and investigated by AFM.

The AFM images display very different process windows for perpendicular orientation of the PXSTs. The Cl-substituted PXST resulted in perpendicular cylinders for block film thicknesses of 30 to 35 nm, and the PXST with a Br substituent had a process window from 23 to 41 nm (Figure 5). These process window results are similar to other polymeric surface treatments reported by Nealey [14] and Hawker and Russell [10, 15, 16]. This leads to the conclusion that a PXST need not consist of the same monomers as the BC being coated.

DESCRIPTION OF ILLUSTRATIVE EMBODIMENTS

It is not intended that the present invention be limited to specific block polymers. However, to illustrate the invention, examples of various copolymers are provided. In one embodiment, the invention relates to the synthesis of the polystyrene-containing block copolymer "PS-b-PMMA." PS-b-PMMA was anionically synthesized via standard Schlenk line techniques (Figure 1) [11, 12]. ¹H-NMR showed the resulting polymer is 31 mol% PMMA, which corresponds to a volume fraction of 0.27 [17]. This is within the range for cylinder morphology [1]. The Mn of the PS aliquot was 45.8 kDa with a PDI of 1.18; the total molecular weight was 65.6 kDa with a PDI of 1.18. Figure 2 shows GPC chromatograms of the PS aliquot and PS-b-PMMA.

In one embodiment, the invention relates to the synthesis of P(SR)-r-P(SBnAz). In a procedure similar to Hawker et al. [9], several commercially available styrene derivatives were radically copolymerized with vinyl benzyl chloride to investigate the role of substituents on the surface energy of PS. Upon isolation of **2**, nucleophilic substitution of the chloride with azide ion led to cross-linkable polymers **3** (Figure 3).

The presence of the azide was confirmed by IR, and the resulting polymers are described in Table 1.

GENERAL MATERIALS AND METHODS

5 **Materials.** All reagents were purchased from Sigma-Aldrich Chemical Co. and used without further purification unless otherwise noted. THF was purchased from JT Baker. 100 mm silicon wafers were purchased from Silicon Quest International.

10 **Instrumentation.** All ^1H and ^{13}C NMR spectra were recorded on a Varian Unity Plus 400 MHz instrument. All chemical shifts are reported in ppm downfield from TMS using the residual protonated solvent as an internal standard (CDCl_3 , ^1H 7.26 ppm and ^{13}C 77.0 ppm). Molecular weight and polydispersity data were measured using an Agilent 1100 Series Isopump and Autosampler and a Viscotek Model 302 TETRA Detector Platform with 3 I-series Mixed Bed High MW columns against polystyrene standards. Polymer solutions were filtered with 0.20 μm PTFE filters prior to spin
15 coating. Films were spin coated and baked on a Brewer CEE 100CB Spincoater & Hotplate. Film thicknesses were determined with a J.A. Woollam Co, Inc. VB 400 VASE Ellipsometer using wavelengths from 382 to 984 nm with a 70° angle of incidence. Contact angles were measured with a Ramé-Hart, inc. NRL C.A. Goniometer (Model #100-00). A Heraeus Vacutherm Type VT 6060 P from Kendro was used to
20 thermally anneal the films under reduced pressure. A Digital Instruments Dimension 3100 atomic force microscope with NCHR Pointprobe® Non-Contact Mode tips with a force constant of 42 N/m was used to collect AFM images.

EXAMPLE 1

Synthesis of poly(styrene-*b*-methyl methacrylate) (PS-*b*-PMMA (1))

PS-*b*-PMMA was synthesized as previously reported by sequential anionic polymerization of styrene and methyl methacrylate in THF at -78 °C under Ar atmosphere via standard Schlenk line techniques [11]. The initiator was *sec*-BuLi; diphenyl ethylene was used to properly initiate MMA, and LiCl was added to suppress side reactions during MMA propagation [12].

EXAMPLE 2

10 **P(SR)-*r*-P(SBnAz) (3).** In a procedure adopted from Hawker et al. [9], a substituted styrene (20 mmol) and vinyl benzyl chloride (0.62 mmol) were radically copolymerized in refluxing THF (20 mL) for 48 h with enough AIBN to obtain a theoretical MW of 25 kDa. Once polymer **2** was precipitated in 0 °C MeOH, filtered, and dried *in vacuo*, the mol ratio of substituted styrene to vinyl benzyl chloride was determined by ¹H-NMR.

15 Taking into account this ratio and the Mn as determined by GPC, polymer **2** (1.0 g) and sodium azide (3 equiv/BnCl) were dissolved in DMF (20 mL) and stirred overnight at room temperature (rt). The polymer was precipitated in MeOH, filtered, redissolved in THF (10 mL), and stirred with H₂O (1 mL) to remove any unreacted salts. Finally, the polymer was isolated by precipitation in 0 °C MeOH, filtered, and dried *in vacuo* to

20 yield white powder **3**. Typical yields over these two steps were 50%; IR (KBr) 2100 cm⁻¹. Complete characterization is shown in Table 1.

EXAMPLE 3

Surface Treatment with PXSTs. A film of P(SR)-*r*-P(SBnAz) was spin coated from a

25 1.0 wt% solution in toluene at 3770 rpm for 30 sec onto a wafer that had been rinsed

with IPA and acetone. The wafer was immediately baked at 250 °C for 5 min to cross-link the film. The wafer was then submerged in toluene for 2 min, blown dry, submerged again for 2 min, and blown dry. Typical film thicknesses as determined by ellipsometry were 15 -20 nm.

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EXAMPLE 4

Surface Energy Measurements by Goniometry. Contact angles were measured with H₂O, diiodomethane, and glycerol, and analyzed via the Young-Dupre equation (**Eq 1**) and the Acid-Base Surface Energy Model (**Eq 2**) [18].

$$10 \quad \gamma_{SV} = \gamma_{SL} + \gamma_{LV} \cos \theta - \pi_{eq} \quad \text{Eq 1}$$

γ_{SV} is the surface energy of the solid-vapor interface, γ_{SL} is the interfacial energy of the solid-liquid interface, γ_{LV} is the surface tension of the fluid, θ is the angle between the solid and liquid, and π_{eq} is the equilibrium spreading pressure, which is approximately zero for polymeric surfaces.

$$15 \quad \gamma_{12} = \gamma_{12}^{LW} + \gamma_{12}^{AB}$$

Eq 2

$$- \gamma_2 \cos \theta = \gamma_2^{LW} - 2(\gamma_1^{LW} \gamma_2^{LW})^{1/2} + 2[(\gamma_2^{P+} \gamma_2^{P-})^{1/2} - (\gamma_1^{P+} \gamma_2^{P-})^{1/2} - (\gamma_1^{P-} \gamma_2^{P+})^{1/2}] \quad \text{Eq 3}$$

20 Briefly, **Eq 2** describes the interfacial energy between two components (γ_{12}) as the sum of the dispersion (γ_{12}^{LW}) and acid-base components (γ_{12}^{AB}). **Eq 3** relates the surface energy of the film and cosine of the contact angle ($-\gamma_2 \cos \theta$) to the dispersion (γ_2^{LW}), Lewis acid (γ_2^{P+}), and Lewis base components (γ_2^{P-}). Using literature values for H₂O, diiodomethane, and glycerol, a system of equations was solved to obtain the surface
25 energy of the PXST films.

Spin Coating and Annealing. A clean, surface-treated wafer was spin coated with a film of PS-b-PMMA from toluene at various speeds and concentrations to give 20 - 70 nm films as determined by ellipsometry. Once cast, the wafer shards were annealed at

5 170 °C under reduced pressure for 12-18 h.

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Claims:

1. A method, comprising:
 - 5 a. providing: i) a crosslinkable polymer comprising first and second monomers, ii) a block copolymer comprising third and fourth monomers, wherein said third and fourth monomers are chemically different from said first and second monomers;
 - b. coating a surface with said crosslinkable polymer to create a first film;
 - 10 c. treating said first film under conditions such that crosslinkable polymer is crosslinked;
 - d. coating said first film with said block copolymer to create a second film; and
 - e. treating said second film under conditions such that nanostructures form,
15 wherein the shape of the nanostructures is controlled by the chemical nature of said first film.
2. The method of claim 1, wherein the nanostructures comprise cylindrical
structures, said cylindrical structures being substantially vertically aligned with
20 respect to the plane of the first film.
3. The method of Claim 1, wherein said coating of step b) comprises spin coating.

4. The method of Claim 3, wherein the thickness of said first film is between 10 and 30 nm.
5. The method of Claim 4, wherein said thickness of said first film is between 15 and 20 nm.
6. The method of Claim 1, wherein said crosslinkable polymer comprises an azido group on said first or second monomer.
7. The method of Claim 6, wherein said treating of said first film in step c) comprises heating.
8. The method of Claim 1, wherein said third monomer is styrene and said block copolymer comprises polystyrene.
9. The method of Claim 8, wherein said block copolymer is a polystyrene-block-poly(methyl methacrylate) copolymer.
10. The method of Claim 1, wherein said coating of said first film in step d) comprises spin coating.
11. The method of Claim 10, wherein the thickness of said second film is between 10 and 100 nm.

12. The method of Claim 11, wherein said thickness of said second film is between 20 and 70 nm.

13. The method of Claim 1, wherein the treating of step e) comprises heating.

5

14. A composition, comprising a second polymer film coated on a first polymer film, said first polymer film comprising first and second monomers, said second polymer film comprising third and fourth monomers, wherein said third and fourth monomers are chemically different from said first and second monomers.

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15. The composition of Claim 14, wherein said second film comprises nanostructures, said structures controlled by the chemical nature of said first film.

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16. The composition of Claim 15, wherein said nanostructures comprise cylindrical nanostructures, said cylindrical nanostructures being substantially vertically aligned with respect to the plane of the first film.

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17. The composition of Claim 14, wherein said second film comprises a polystyrene-block-poly(methyl methacrylate) copolymer.

18. The composition of Claim 14, wherein said first polymer film is coated on a surface.

19. The composition of Claim 14, wherein said first polymer film is crosslinked.

20. The composition of Claim 14, wherein the thickness of said first film is between
10 and 30 nm.

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21. The composition of Claim 20, wherein said thickness of said first film is
between 15 and 20 nm.

22. The composition of Claim 14, wherein the thickness of said second film is
10 between 10 and 100 nm.

23. The composition of Claim 22, wherein said thickness of said second film is
between 20 and 70 nm.